



**THE DATASHEET OF  
MBRA2H100T3G**



# MBRS2H100T3G, NBR2H100T3G, MBRA2H100T3G, NRVBA2H100T3G SBRA2H100T3G



ON Semiconductor®

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## Surface Mount Schottky Power Rectifier

### SMA/SMB Power Surface Mount Package

This device employs the Schottky Barrier principle in a metal-to-silicon power rectifier. Features epitaxial construction with oxide passivation and metal overlay contact. Ideally suited for low voltage, high frequency switching power supplies; free wheeling diodes and polarity protection diodes.

#### Features

- Compact Package with J-Bend Leads Ideal for Automated Handling
- Highly Stable Oxide Passivated Junction
- Guard-Ring for Overvoltage Protection
- Low Forward Voltage Drop
- NBR and NRVB Prefixes for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable\*

#### Mechanical Characteristics

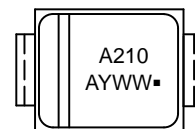
- Case: Molded Epoxy
- Epoxy Meets UL 94 V-0 @ 0.125 in
- Weight: 70 mg (SMA), 95 mg (SMB) (Approximately)
- Cathode Polarity Band
- Lead and Mounting Surface Temperature for Soldering Purposes: 260°C Max. for 10 Seconds
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- ESD Ratings:
  - ◆ Machine Model = C
  - ◆ Human Body Model = 3B
- These Devices are Pb-Free and are RoHS Compliant
- Device Meets MSL1 Requirements

### SCHOTTKY BARRIER RECTIFIER 2.0 AMPERES, 100 VOLTS

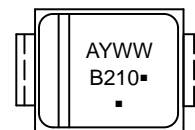
#### MARKING DIAGRAMS



SMA  
CASE 403D



SMB  
CASE 403A



A210 = MBRA2H100T3G  
NRVBA2H100T3G

B210 = MBRS2H100T3G  
NBR2H100T3G

A = Assembly Location

Y = Year

WW = Work Week

■ = Pb-Free Package

(Note: Microdot may be in either location)

\*\*The Assembly Location code (A) is front side optional. In cases where the Assembly Location is stamped in the package, the front side assembly code may be blank.

#### ORDERING INFORMATION

Device	Package	Shipping†
MBRA2H100T3G, NRVBA2H100T3G*	SMA (Pb-Free)	5,000 / Tape & Reel
MBRS2H100T3G, NBR2H100T3G*, NBR2H100T3G-VF01*, SBRA2H100T3G	SMB (Pb-Free)	2,500 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# MBRS2H100T3G, NBR2H100T3G, MBRA2H100T3G, NRVBA2H100T3G

## MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$V_{RRM}$ $V_{RWM}$ $V_R$	100	V
Average Rectified Forward Current ( $T_L = 150^\circ\text{C}$ )	$I_O$	2.0	A
Non-Repetitive Peak Surge Current (Surge Applied at Rated Load Conditions Halfwave, Single Phase, 60 Hz)	$I_{FSM}$	130	A
Storage Temperature Range	$T_{stg}$	-65 to +175	$^\circ\text{C}$
Operating Junction Temperature (Note 1)	$T_J$	-65 to +175	$^\circ\text{C}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- The heat generated must be less than the thermal conductivity from Junction-to-Ambient:  $dP_D/dT_J < 1/R_{\theta JA}$ .

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance, Junction-to-Lead (Note 2) MBRA2H100T3G, NRVBA2H100T3G MBRS2H100T3G, NBR2H100T3G	$\Psi_{JCL}$	14 12	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient (Note 2) MBRA2H100T3G, NRVBA2H100T3G MBRS2H100T3G, NBR2H100T3G	$R_{\theta JA}$	75 71	$^\circ\text{C/W}$
Thermal Resistance, Junction-to-Ambient (Note 3) MBRA2H100T3G, NRVBA2H100T3G MBRS2H100T3G, NBR2H100T3G	$R_{\theta JA}$	275 230	$^\circ\text{C/W}$

- Mounted with 700 mm square copper pad size (Approximately 1 inch square) 1 oz FR4 Board.
- Mounted with minimum recommended pad size 1 oz FR4 Board.

## ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	Value		Unit
		$T_J = 25^\circ\text{C}$	$T_J = 125^\circ\text{C}$	
Maximum Instantaneous Forward Voltage (Note 4) ( $I_F = 2.0\text{ A}$ )	$V_F$	0.79	0.65	V
Maximum Instantaneous Reverse Current (Note 4) ( $V_R = 100\text{ V}$ )	$I_R$	0.008	1.5	mA

- Pulse Test: Pulse Width  $\leq 380\ \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

TYPICAL CHARACTERISTICS

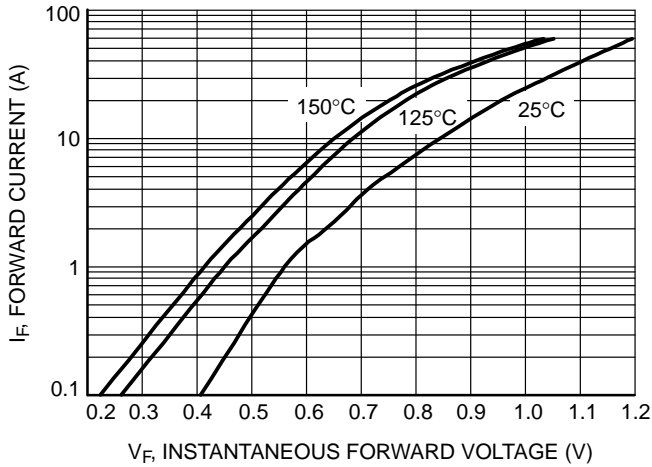


Figure 1. Typical Forward Voltage

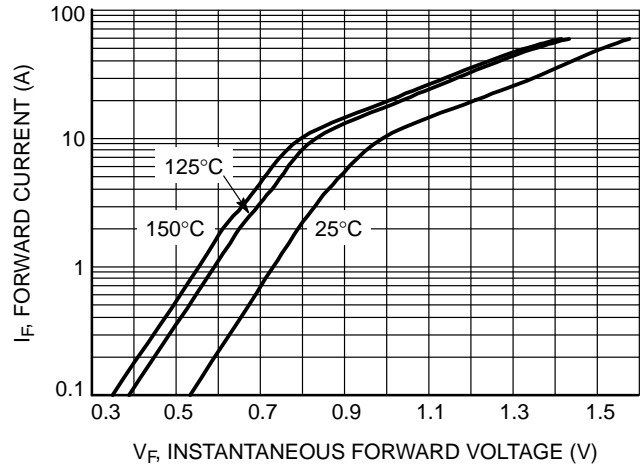


Figure 2. Maximum Forward Voltage

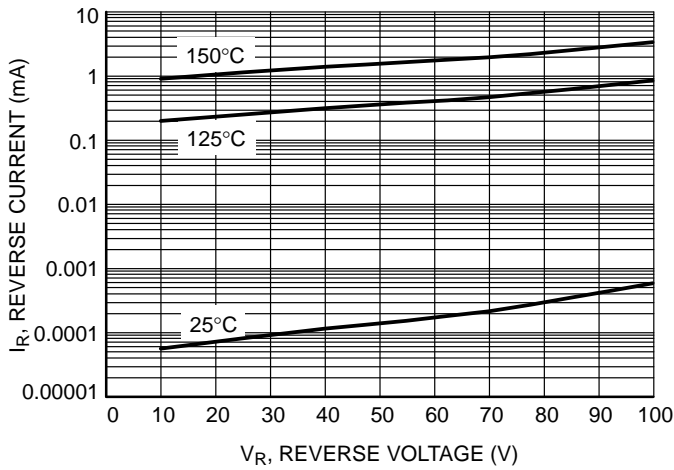


Figure 3. Typical Reverse Current

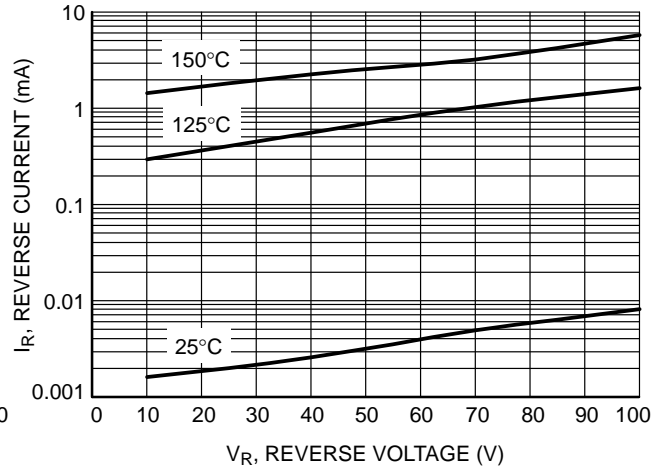


Figure 4. Maximum Reverse Current

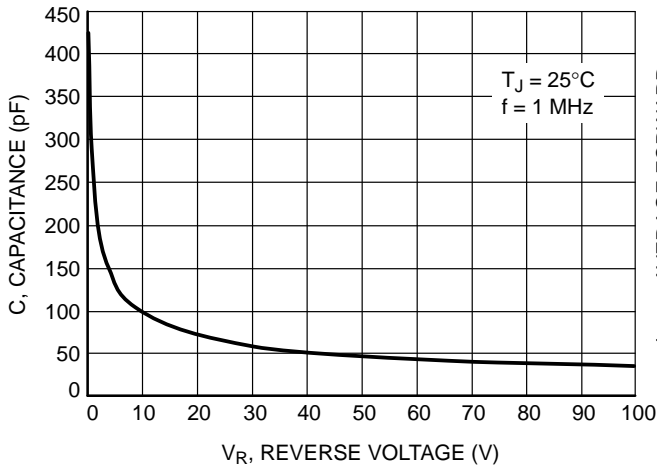


Figure 5. Typical Capacitance

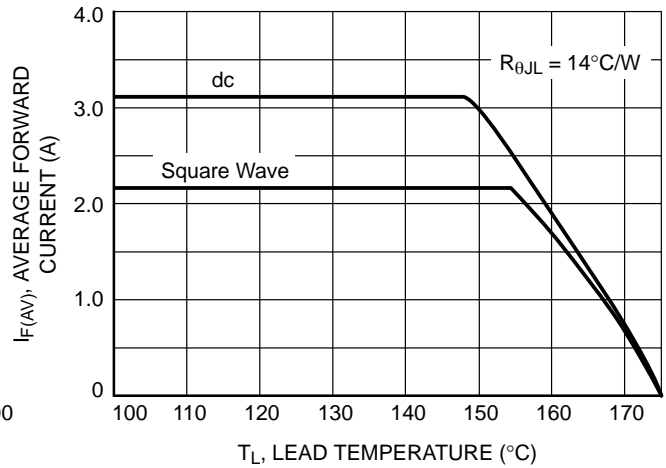


Figure 6. Current Derating – Lead

# MBRS2H100T3G, NBR2H100T3G, MBRA2H100T3G, NRVBA2H100T3G

## TYPICAL CHARACTERISTICS

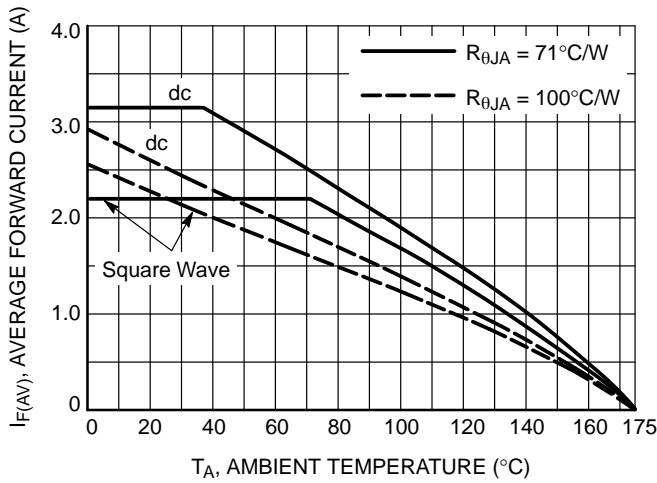


Figure 7. Current Derating, Ambient

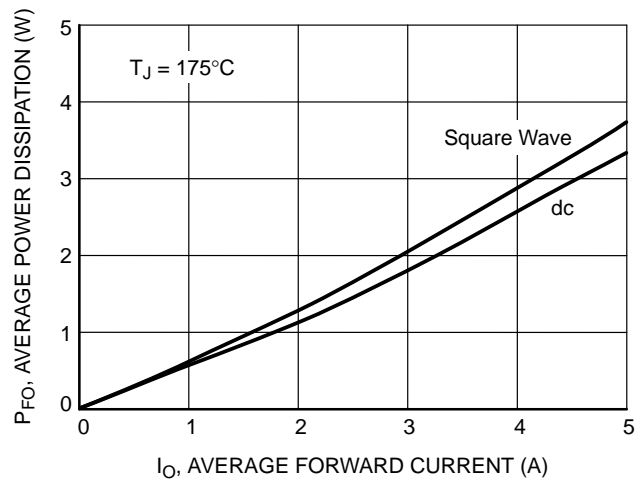


Figure 8. Maximum Forward Power Dissipation

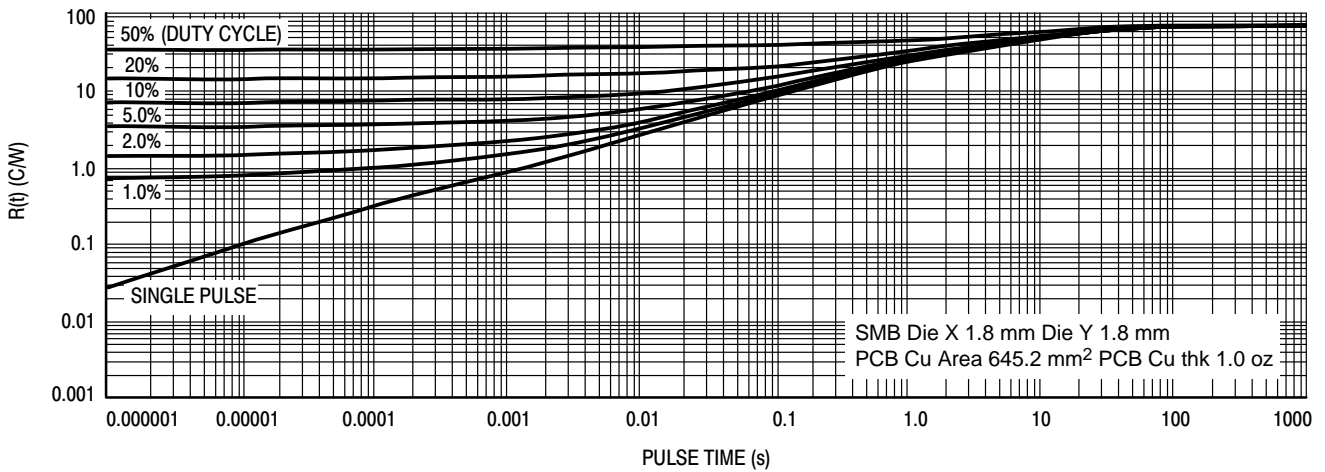


Figure 9. Thermal Response, Junction-to-Ambient (1 inch pad) – MBRS2H100T3G/NBR2H100T3G

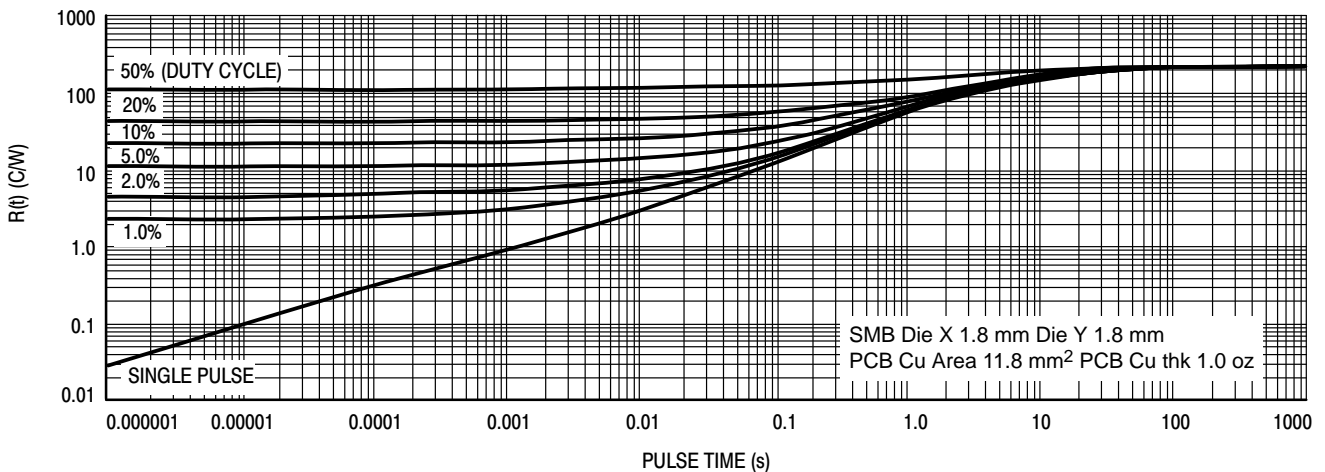
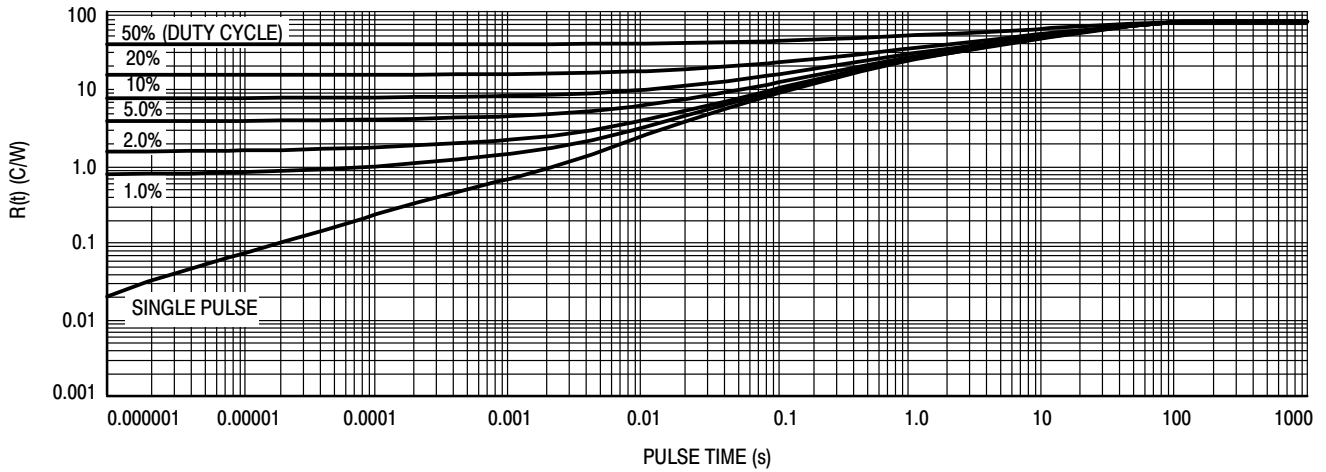


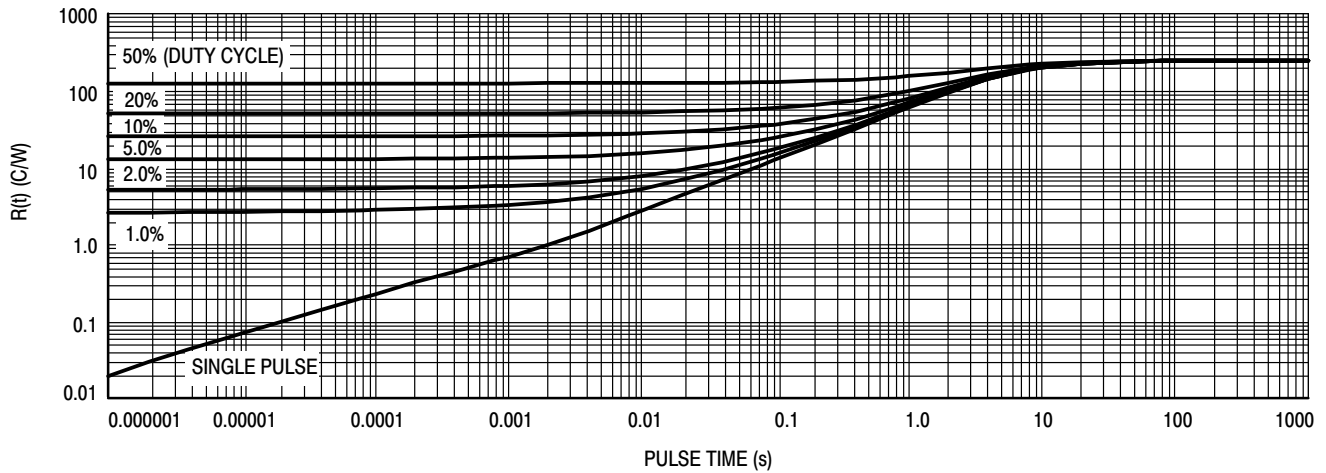
Figure 10. Thermal Response, Junction-to-Ambient (min pad) – MBRS2H100T3G/NBR2H100T3G

**MBRS2H100T3G, NBR2H100T3G, MBRA2H100T3G, NRVBA2H100T3G**

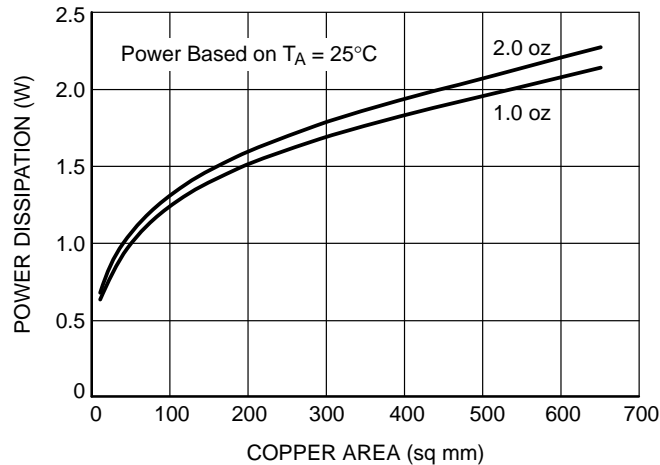
**TYPICAL CHARACTERISTICS**



**Figure 11. Thermal Response, Junction-to-Ambient (1 inch pad) – MBRA2H100T3G/NRVBA2H100T3G**



**Figure 12. Thermal Response, Junction-to-Ambient (min pad) – MBRA2H100T3G/NRVBA2H100T3G**

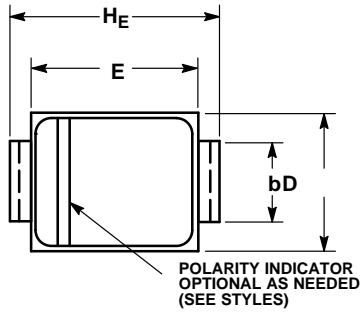


**Figure 13.  $P_D$ , Junction-to-Ambient (URS copper area)**

# MBRS2H100T3G, NBR2H100T3G, MBRA2H100T3G, NRVBA2H100T3G

## PACKAGE DIMENSIONS

SMA  
CASE 403D  
ISSUE H



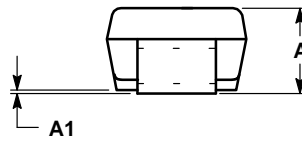
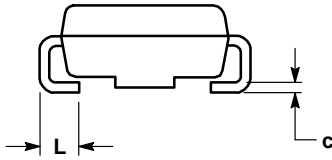
NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L.

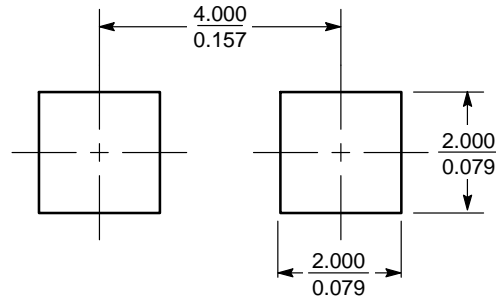
DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.97	2.10	2.20	0.078	0.083	0.087
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.27	1.45	1.63	0.050	0.057	0.064
c	0.15	0.28	0.41	0.006	0.011	0.016
D	2.29	2.60	2.92	0.090	0.103	0.115
E	4.06	4.32	4.57	0.160	0.170	0.180
HE	4.83	5.21	5.59	0.190	0.205	0.220
L	0.76	1.14	1.52	0.030	0.045	0.060

STYLE 1:

- PIN 1. CATHODE (POLARITY BAND)
- ANODE



### SOLDERING FOOTPRINT\*



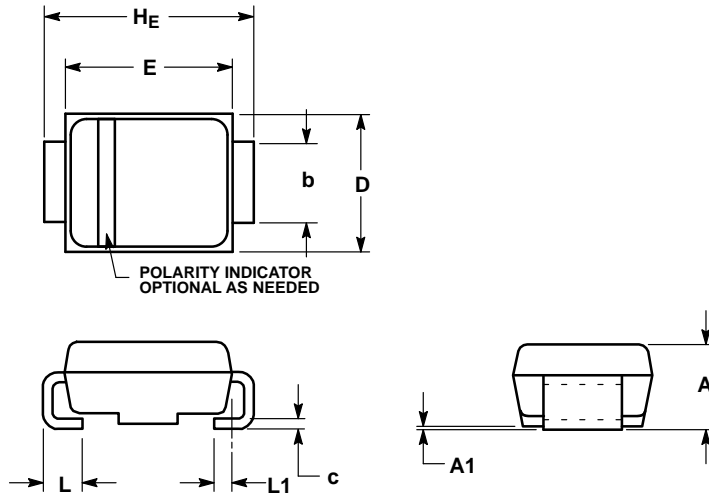
SCALE 8:1 ( $\frac{\text{mm}}{\text{inches}}$ )

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

# MBRS2H100T3G, NBR2H100T3G, MBRA2H100T3G, NRVBA2H100T3G

## PACKAGE DIMENSIONS

### SMB CASE 403A-03 ISSUE J

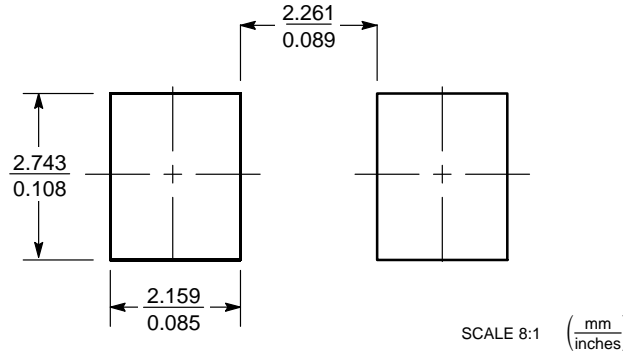


#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION b SHALL BE MEASURED WITHIN DIMENSION L1.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.95	2.30	2.47	0.077	0.091	0.097
A1	0.05	0.10	0.20	0.002	0.004	0.008
b	1.96	2.03	2.20	0.077	0.080	0.087
c	0.15	0.23	0.31	0.006	0.009	0.012
D	3.30	3.56	3.95	0.130	0.140	0.156
E	4.06	4.32	4.60	0.160	0.170	0.181
HE	5.21	5.44	5.60	0.205	0.214	0.220
L	0.76	1.02	1.60	0.030	0.040	0.063
L1	0.51 REF			0.020 REF		

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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